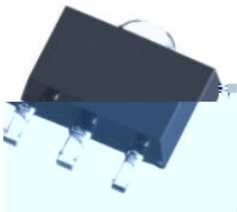
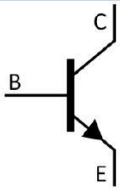


SOT-89          NPN          Silicon NPN transistor in a SOT-89 Plastic Package.

,          MMBT5401T  
 High voltage, complementary pair with MMBT5401T. Halogen-free Product.

General purpose high voltage amplifier.



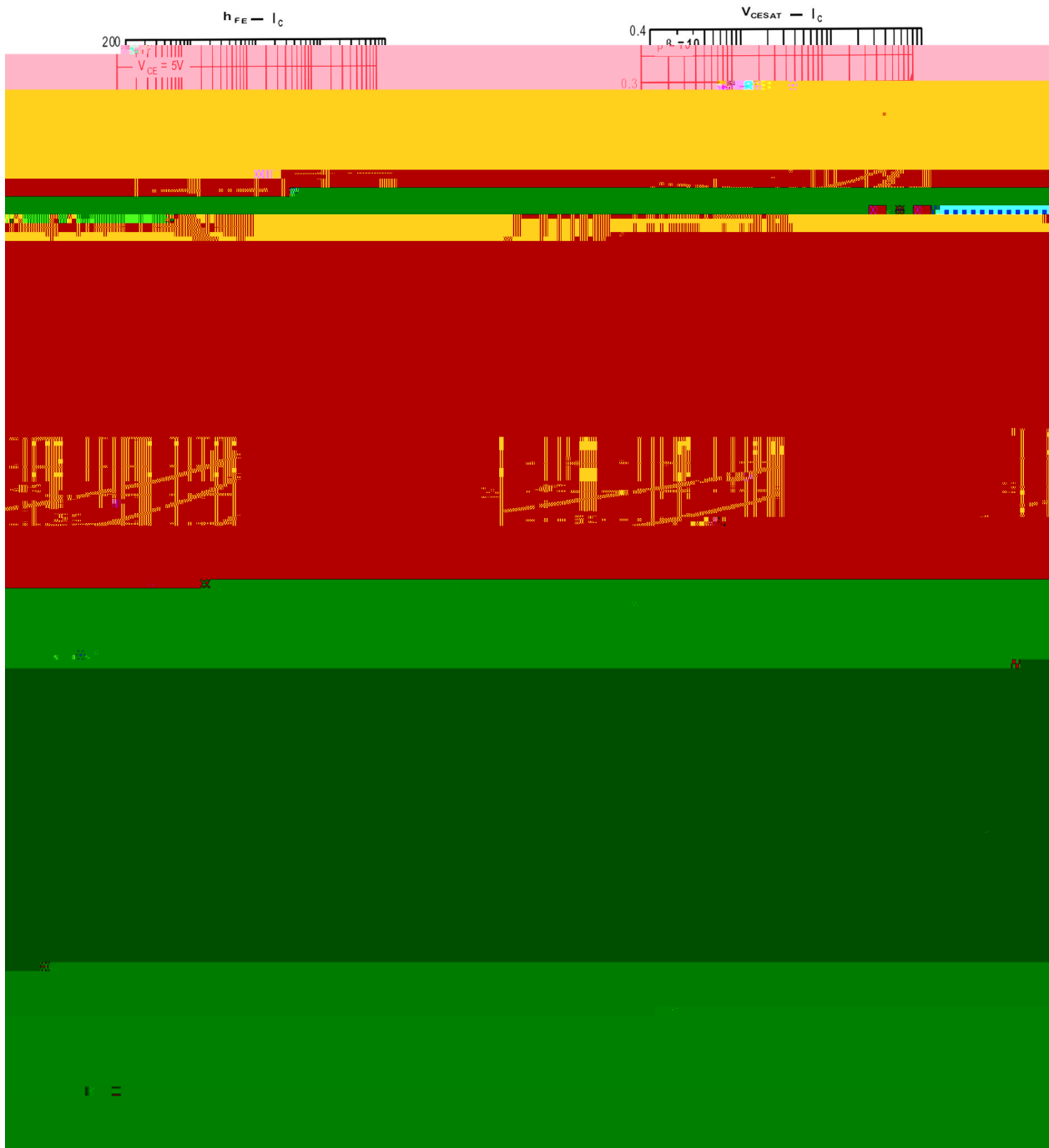
PIN1 Base          PIN 2 Collector          PIN 3 Emitter

| $h_{FE}$ Classifications<br>Symbol | A      | B       | C       |
|------------------------------------|--------|---------|---------|
| $h_{FE}$ Range                     | 50 150 | 100 300 | 200 400 |
| Marking                            | HG1A*  | HG1B*   | HG1C*   |

| Parameter                      | Symbol    | Rating  | Unit |
|--------------------------------|-----------|---------|------|
| Collector to Base Voltage      | $V_{CBO}$ | 180     | V    |
| Collector to Emitter Voltage   | $V_{CEO}$ | 160     | V    |
| Emitter to Base Voltage        | $V_{EBO}$ | 6.0     | V    |
| Collector Current - Continuous | $I_C$     | 600     | mA   |
| Collector Base - Continuous    | $I_B$     | 300     | mA   |
| Collector Power Dissipation    | $P_C$     | 500     | mW   |
| Junction Temperature           | $T_j$     | 150     | °C   |
| Storage Temperature Range      | $T_{stg}$ | -55 150 | °C   |

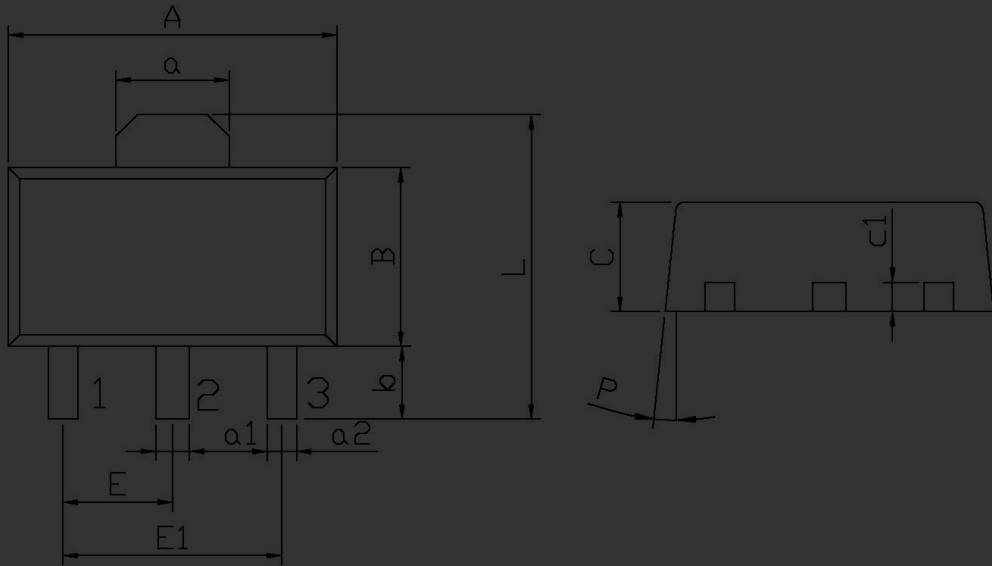
| Parameter                               | Symbol            | Test Conditions           | Min | Typ  | Max  | Unit    |
|---|-------------------|---------------------------|-----|------|------|---------|
| Collector Cut-Off Current               | $I_{CBO}$         | $V_{CB}=180V$ $I_E=0$     |     |      | 0.1  | $\mu A$ |
| Emitter Base Cut-Off Current            | $I_{EBO}$         | $V_{EB}=6.0V$ $I_C=0$     |     |      | 0.1  | $\mu A$ |
| DC Current Gain                         | $h_{FE(1)}$       | $V_{CE}=5.0V$ $I_C=10mA$  | 50  | 200  | 400  |         |
|   | $h_{FE(2)}$       | $V_{CE}=5.0V$ $I_C=50mA$  | 20  | 160  |      |         |
|   | $h_{FE(3)}$       | $V_{CE}=5.0V$ $I_C=1.0mA$ | 40  | 190  |      |         |
| Collector to Emitter Saturation Voltage | $V_{CE(sat) (1)}$ | $I_C=10mA$ $I_B=1.0mA$    |     | 0.06 | 0.15 | V       |
|   | $V_{CE(sat) (2)}$ | $I_C=50mA$ $I_B=5.0mA$    |     | 0.09 | 0.3  | V       |
| Emitter to Base Saturation Voltage      | $V_{BE(sat) (1)}$ | $I_C=10mA$ $I_B=1.0mA$    |     | 0.7  | 1.0  | V       |
|   | $V_{BE(sat) (2)}$ | $I_C=50mA$ $I_B=5.0mA$    |     | 0.8  | 1.0  | V       |
| Emitter to Base Voltage                 | $V_{BE}$          | $V_{CE}=5.0V$ $I_C=10mA$  |     | 0.68 | 0.75 | V       |

E

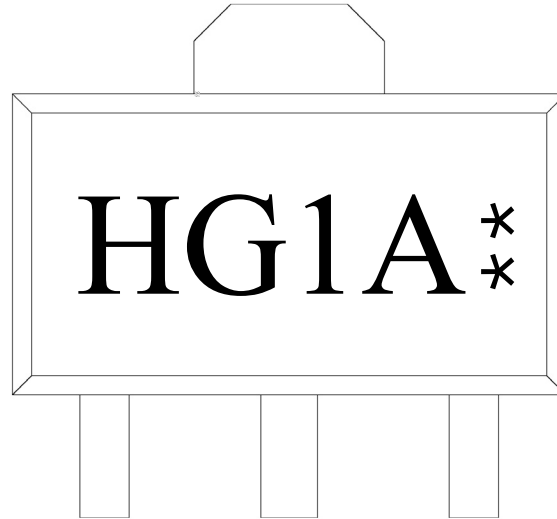


SOT-89

单位: mm



| Symbol | Dimensions In Millimeters |      | Symbol | Dimensions In Millimeters |      |
|--------|---------------------------|------|--------|---------------------------|------|
|        | Min                       | Max  |        | Min                       | Max  |
| A      | 4.4                       | 4.7  | a1     | 0.36                      | 0.56 |
| B      | 2.35                      | 2.65 | a2     | 0.30                      | 0.50 |



H

G1

A:  $h_{FE}$

\*\*

Note:

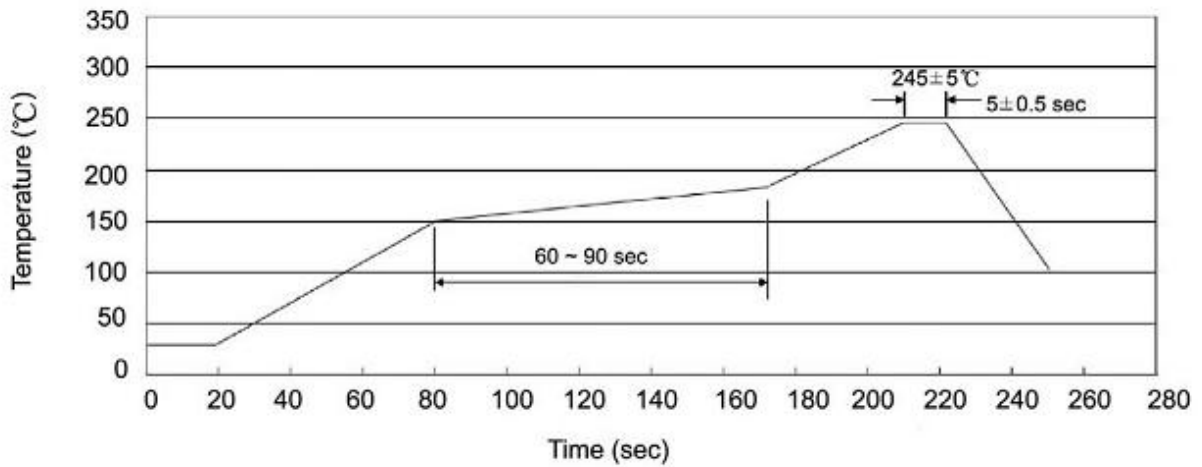
H: Company Code.

G1: Product Type.

A:  $h_{FE}$  Classifications Symbol

\*\* : Lot No. Code, code change with Lot No.

**Temperature Profile for IR Reflow Soldering(Pb-Free)**



Note:

- |   |       |     |           |        |   |
|---|-------|-----|-----------|--------|---|
| 1 | 150   | 180 | 60        | 90sec; | 1.Preheating:150~180 , Time:60~90sec.   |
| 2 | 245±5 |     | 5±0.5sec; |        | 2.Peak Temp.:245±5 , Duration:5±0.5sec. |
| 3 |       | 2   | 10        | /sec.  | 3. Cooling Speed: 2~10 /sec.            |

260±5

10±1 sec.

Temp.:260±5°C

Time:10±1 sec

/ REEL

| Package Type<br>封装形式 | Units 包装数量 |     |    |    |    | Dimension 包装尺寸 (unit: mm <sup>3</sup> ) |   |  |
|----------------------|------------|-----|----|----|----|---|---|--|
|                      | 只卷盘        | 卷盘盒 | 只盒 | 盒箱 | 只箱 | 盒                                       | 箱 |  |
|                      |            |     |    |    |    |   |   |  |